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	Filing Date		2006-07-25
	First Named Inventor	GRUDIN, Oleg	
	Art Unit	3729	
	Examiner Name	PHAN, Thiem D.	
Attorney Docket Number		14836-14US AD/ad	

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	3	J. Babcock, P. Francis, R. Bashir, A. Kabir, D. Shroder, M. Lee, T. Dhayagude, W. Yindeepol, S. Prasad, A. Kalnitskiy, M. Thomas, H. Haggag, K. Egan, A. Bergemont, P. Jansen, "Precision Electrical Trimming of very Low TCR Poly-SiGe Resistors", IEEE Electron. Dev. Letters, vol. 21 (2000), 6, pp.283-285	<input type="checkbox"/>

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